

First passage time in multistep stochastic processes with applications to dust charging

B. Shotorban *

Department of Mechanical and Aerospace Engineering, The University of Alabama in Huntsville, Huntsville, Alabama 35899, USA



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An approach was developed to describe the first passage time (FPT) in multistep stochastic processes with discrete states governed by a master equation (ME). The approach is an extension of the totally absorbing boundary approach given for calculation of FPT in one-step processes [N. G. Van Kampen, *Stochastic Processes in Physics and Chemistry* (Elsevier Science Publishers, North Holland, Amsterdam, 2007)] to include multistep processes where jumps are not restricted to adjacent sites. In addition, a Fokker-Planck equation (FPE) was derived from the multistep ME, assuming the continuity of the state variable. The developed approach and an FPE based approach [C. W. Gardiner, *Handbook of Stochastic Methods*, 3rd ed. (Springer-Verlag, New York, 2004)] were used to find the mean first passage time (MFPT) of the transition between the negative and positive stable macrostates of dust grain charge when the charging process was bistable. The dust was in a plasma and charged by collecting ions and electrons, and emitting secondary electrons. The MFPTs for the transitioning of grain charge from one macrostate to the other were calculated by the two approaches for a range of grain sizes. Both approaches produced very similar results for the same grain except for when it was very small. The difference between MFPTs of two approaches for very small grains was attributed to the failure of the charge continuity assumption in the FPE description. For a given grain, the MFPT for a transition from the negative macrostate to the positive one was substantially larger than that for a transition in a reverse order. The normalized MFPT for a transition from the positive to the negative macrostate showed little sensitivity to the grain radius. For a reverse transition, with the increase of the grain radius, it dropped first and then increased. The probability density function of FPT was substantially wider for a transition from the positive to the negative macrostate, as compared to a reverse transition.

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I. INTRODUCTION

An intrinsic noise, characterized by random fluctuations, is inherent in the systems with particles [1]. An electrically charged dust grain is an example of such systems where the charging is attributed to the ion and electron particles that are attached to or emitted from the grain. The electron and ion attachment events occur at time intervals characterized by randomness. Hence, the net charge of the grain exhibits random fluctuations over time. Intrinsic noises can be described by a master equation (ME) governing the probability density function (PDF) of the state of the system [1]. The ME of the dust charging system admits different forms where the functionality of the transition probability rates in terms of the charge state depends on the mechanisms that are responsible for charging. These forms are previously constructed when the charging mechanisms are the collisional collection of electrons and singly charged positive ions [2–5], the collisional collection of electrons and multiply charged ions [6,7], and the collisional collection of ions and electrons combined with the secondary emission of electrons (SEE) from the grain [8–10].

Intrinsic charge fluctuations of a grain were the subject of several investigations [2–18]. Let $Z(t)$ indicate the instantaneous net elementary charge (charge state) of the grain. It is an integer variable and a function of time t . When, for

example, five singly charged positive ions and eight electrons are collected on the grain at a given time, the grain is at charge state $Z = +5 - 8 = -3$. Here, $Z(t)$ experiences step-wise variation over time, because it can only have integer values, as a consequence of discreteness nature of charge. Morfill *et al.* [11] suggested that intrinsic fluctuations of $Z(t)$ follows $Z_{\text{rms}}^2 \propto |\langle Z \rangle|$, where $\langle Z \rangle$ and Z_{rms}^2 denote the mean and variance of $Z(t)$, respectively. At the limit of large $|Z(t)|$, the charge is assumed to continuously vary and, accordingly, the grain charge probability distribution is shown to be Gaussian with the mean and variance found to respect the proportionality correlation above [2,5,6]. This Gaussianity was determined for situations where the mechanism of charging was the collisional collection of plasma particles. A similar finding was also made for situations where the thermionic emission or UV irradiation mechanisms are active dust charging mechanisms in addition to the collisional collection mechanism [13]. On the other hand, it was shown that when $|Z(t)|$ is smaller than tens of elementary charges, the charge probability distribution can significantly deviate from Gaussianity [2,5]. This deviation is attributed to the significance of charge discreteness effects in the time evolution of $|Z(t)|$ when it is small. The smaller $|Z(t)|$ is, the larger the deviation is. In the studies reviewed above, the dust charge fluctuations were stable, a feature characterized by fluctuations around a fixed stable point (stationary stable macrostate).

It was shown [10] that if both collisional collection and SEE mechanisms were active, charge fluctuations could be

*babak.shotorban@uah.edu

unstable. This instability was characterized by a substantial deviation of the grain charge PDF from Gaussianity in some cases. Moreover, it was shown that if the SEE was active, fluctuations could be bistable. This bistability is associated with a bifurcation phenomenon of the grain charge, known from the investigations of Meyer-Vernet [19] and Horányi *et al.* [20] who accounted for SEE while neglecting intrinsic charge fluctuations. In this phenomenon, two identical grains in the same plasma environment exhibit two distinct (mean) charge values, one positive and the other negative. Shotorban [10] showed that these values correspond to two macrostates [1] between which the charge intrinsic fluctuations of a grain can switch. This behavior is known as metastability in stochastic processes and it is a state where the fluctuations are characterized by two distinct time scales—one associated with the fluctuations at either macrostate and the other with the spontaneous transition between the macrostates. It was shown that a switch from the negative macrostate to the positive macrostate is attributed to a sequence of incidents with ion attachment or primary electron attachment that resulted in emission of secondary electrons [10]. On the other hand, a reverse switch is attributed to a sequence of incidents most of which are the attachments of primary electrons that result in no emission of secondary electrons.

The current study was motivated by a need to determine the first-passage time (FPT) [1] of grain charge fluctuations: Starting from a given charge, how long does it take for the grain to possess a specified charge? The FPT is of particular interest in metastable fluctuations, as it quantifies the time scales of the transitions between the macrostates. The FPT is a random quantity whose behavior can be described by the calculation of its statistical properties. For example, the growth and dissipation times, calculated by Matsoukas and Russell [4] for grain charging due to collisional collection of plasma particles, are special cases of the mean first passage time (MFPT). The growth time is defined as the mean time for the transition from the mean charge to a specified charge, and the dissipation time is the mean time to revert from the specified charge to the mean charge. Recently, Matthews *et al.* [18] used Matsoukas and Russell's [4] formulation for the growth and dissipation times, to validate a discrete stochastic model for the charging of aggregate grains. This formulation is limited to the grain charging described by a linear Fokker-Planck equation (FPE) [1] derived from the ME of a one-step process. In the next section, mathematical approaches are proposed to calculate the FPT of multistep processes. Then, they are used to investigate the FPTs in the grain charging system with a focus on bistable situations.

II. FIRST PASSAGE TIME IN MULTISTEP PROCESSES

Consider a stochastic process with a discrete set of states governed by the following master equation:

$$\frac{dP(Z)}{dt} = \sum_{n=1}^N [r_n(Z+n)P(Z+n) - r_n(Z)P(Z)] + \sum_{n=1}^M [g_n(Z-n)P(Z-n) - g_n(Z)P(Z)], \quad (1)$$

where Z is an integer indicating the state variable (site), e.g., the net elementary charge possessed by a grain, and $P(Z)$ is the probability density function. Here, $r_n(Z)$ is the probability per unit time that, being at Z a jump occurs to $Z - n$ and $g_n(Z)$ is the probability per unit time that, being at Z , a jump occurs to $Z + n$. The process modeled by Eq. (1) can be regarded as a “multistep process”, a generalized notion of the one-step process [1], where jumps can also occur between nonadjacent sites. The change of the grain charge by multiple units as a result of collecting multiply charged ions [21] is an example of a jump between nonadjacent sites [6,7,9]. The other example is when multiple secondary electrons are emitted when a primary electron impacts the grain [6,9]. The one-step process master equation is a special case of Eq. (1) with $N = M = 1$. The master equations formulated for grain charging in multicomponent plasma [6] and in cases where the SEE is active [10], can be readily recast in the form given in Eq. (1), as illustrated in Sec. III.

The notion of the macroscopic or phenomenological equation illustrated by Van Kampen [1] for one-step processes is extended here to include multistep processes. That is a deterministic differential equation where the fluctuations of $Z(t)$ is ignored and treated as a non-stochastic quantity. An approach to obtain this equation is to multiply master Eq. (1) by Z and sum over Z :

$$\frac{d\langle Z \rangle}{dt} = - \sum_{n=1}^N n \langle r_n(Z) \rangle + \sum_{n=1}^M n \langle g_n(Z) \rangle, \quad (2)$$

where $\langle \rangle$ indicates the mean defined for a function such as $\alpha(Z)$ by $\langle \alpha(Z) \rangle = \sum_Z \alpha(Z)P(Z)$. In the derivation of Eq. (2), the index shift identity of the summation manipulation rule is used and $P(Z) = 0$ is assumed at the boundaries. Unless $r_n(Z)$ and $g_n(Z)$ are linear functions of Z , Eq. (2) is not a closed equation. However, if they are nonlinear, they may be expanded about $\langle Z \rangle$, e.g.,

$$\langle r_n(Z) \rangle = r_n(\langle Z \rangle) + \frac{1}{2} \langle (Z - \langle Z \rangle)^2 \rangle r_n''(\langle Z \rangle) + \dots \quad (3)$$

This expansion shows that higher-order moments play a role in the time evolution of $\langle Z \rangle$ through Eq. (2). Nonetheless, retaining only the first term in the expansion above and the one for $\langle g_n(Z) \rangle$, the macroscopic equation is obtained

$$\frac{d\mathcal{Z}}{dt} = - \sum_{n=1}^N n r_n(\mathcal{Z}) + \sum_{n=1}^M n g_n(\mathcal{Z}), \quad (4)$$

where $\mathcal{Z} \equiv \langle Z \rangle$.

A. First passage time in master equation

Here, to calculate the FPT, the absorbing boundary approach available for one-step processes [1], is extended to include multistep processes:

Suppose that the system is at state $Z = m$ at $t = 0$. To calculate the escape time to a state $Z \geq R$, where R is located on the right of m , i.e., $m < R$, Eq. (1) is solved in the range $Z < R$ with the initial condition $P(Z) = \delta_{Z,m}$ (Kronecker δ function) while, R is set as the *totally absorbing* boundary condition by setting $P(Z) = 0$ if $Z \geq R$ for all times.

The probability for the system to be at a site in the domain $-\infty < Z < R$ is $\sum_{Z=-\infty}^{R-1} P(Z)$. Now let $f_{R,m}(t)dt$ indicate the probability that starting at site m , the system reaches R or beyond at a time between t and $t + dt$. Then

$$f_{R,m}(t) = -\frac{d}{dt} \sum_{Z=-\infty}^{R-1} P(Z, t) = \sum_{n=1}^M \sum_{Z=R-n}^{R-1} g_n(Z)P(Z, t), \quad (5)$$

where the second line is derived after substitution for $dP(Z)/dt$ from Eq. (1) and the manipulation below:

$$\begin{aligned} \sum_{Z=-\infty}^{R-1} \frac{dP(Z)}{dt} &= \sum_{n=1}^N \sum_{Z=-\infty}^{R-1} [r_n(Z+n)P(Z+n) - r_n(Z)P(Z)] + \sum_{n=1}^M \sum_{Z=-\infty}^{R-1} [g_n(Z-n)P(Z-n) - g_n(Z)P(Z)] \\ &= \sum_{n=1}^N \left[\sum_{Z=-\infty}^{R-1+n} r_n(Z)P(Z) - \sum_{Z=-\infty}^{R-1} r_n(Z)P(Z) \right] + \sum_{n=1}^M \left[\sum_{Z=-\infty}^{R-1-n} g_n(Z)P(Z) - \sum_{Z=-\infty}^{R-1} g_n(Z)P(Z) \right] \\ &= \sum_{n=1}^N \sum_{Z=R}^{R-1+n} r_n(Z)P(Z) - \sum_{n=1}^M \sum_{Z=R-n}^{R-1} g_n(Z)P(Z) \\ &= -\sum_{n=1}^M \sum_{Z=R-n}^{R-1} g_n(Z)P(Z) \end{aligned} \quad (6)$$

noting that in the line before the last one, the first term vanishes since $P(Z) = 0$ for $Z \geq R$.

On the other hand, the total probability of reaching a state at $Z \geq R$ is calculated by

$$\begin{aligned} \pi_{R,m} &= \int_0^\infty f_{R,m}(t)dt \\ &= 1 - \sum_{Z=-\infty}^{R-1} P(Z, t = \infty) \\ &= \sum_{n=1}^M \sum_{Z=R-n}^{R-1} g_n(Z) \int_0^\infty P(Z, t)dt, \end{aligned} \quad (7)$$

and the MFPT is

$$\begin{aligned} \tau_{R,m} &= \frac{1}{\pi_{R,m}} \int_0^\infty t f_{R,m}(t)dt \\ &= \frac{1}{\pi_{R,m}} \sum_{n=1}^M \sum_{Z=R-n}^{R-1} g_n(Z) \int_0^\infty t P(Z, t)dt. \end{aligned} \quad (8)$$

Likewise, for the calculation of the FPT from the state m to the state $Z \leq L$, where $L < m$, Eq. (1) is solved for $P(Z)$ in the domain $L < Z$ with L set as the totally absorbing boundary condition, i.e., $P(Z) = 0$ if $Z \leq L$. Then

$$f_{L,m}(t) = -\frac{d}{dt} \sum_{Z=L+1}^\infty P(Z, t) = \sum_{n=1}^N \sum_{Z=L+1}^{L+n} r_n(Z)P(Z, t). \quad (9)$$

The total probability of reaching L or beyond is

$$\begin{aligned} \pi_{L,m} &= \int_0^\infty f_{L,m}(t)dt \\ &= 1 - \sum_{Z=L+1}^\infty P(Z, t = \infty) \\ &= \sum_{n=1}^N \sum_{Z=L+1}^{L+n} r_n(Z) \int_0^\infty P(Z, t)dt, \end{aligned} \quad (10)$$

and the MFPT is

$$\begin{aligned} \tau_{L,m} &= \frac{1}{\pi_{L,m}} \int_0^\infty t f_{L,m}(t)dt \\ &= \frac{1}{\pi_{L,m}} \sum_{n=1}^N \sum_{Z=L+1}^{L+n} r_n(Z) \int_0^\infty t P(Z, t)dt. \end{aligned} \quad (11)$$

B. Mean first passage time in Fokker-Planck equation

If $r_n(Z)$ and $g_n(Z)$ are smooth functions of Z , i.e., continuous and differentiable a number of times, $g_n(Z)$ slightly change between Z and $Z + M$, and $r_n(Z)$ slightly between Z and $Z + N$, Z may be treated as a continuous variable. Hence, expanding the first terms in the summations in Eq. (1) by Taylor's series and retaining the terms up to the second derivative, e.g.,

$$\begin{aligned} r_n(Z \pm n)P(Z \pm n) &= r_n(Z)P(Z) \pm n \frac{\partial}{\partial Z} [r_n(Z)P(Z)] \\ &\quad + \frac{n^2}{2} \frac{\partial^2}{\partial Z^2} [r_n(Z)P(Z)], \end{aligned} \quad (12)$$

a (forward) Fokker-Planck equation can be derived:

$$\frac{\partial P(Z, t)}{\partial t} = -\frac{\partial}{\partial Z} A(Z)P(Z) + \frac{1}{2} \frac{\partial^2}{\partial Z^2} B(Z)P(Z), \quad (13)$$

where the drift and diffusion functions are

$$A(Z) = -\sum_{n=1}^N n r_n(Z) + \sum_{n=1}^M n g_n(Z), \quad (14)$$

$$B(Z) = \sum_{n=1}^N n^2 r_n(Z) + \sum_{n=1}^M n^2 g_n(Z), \quad (15)$$

respectively. Equation (13) is identical to the Fokker-Planck equation (A1) in Appendix A, where the formulation provided by Gardiner [22] for the calculation of MFPT in the FPE, is illustrated. It is noted that the drift $A(Z)$, given in Eq. (14), is

identical to the right-hand side (r.h.s.) of Eq. (4). On the other hand, since r_n and g_n are positive functions, the positivity of the diffusion coefficient $B(Z)$ is secured in Eq. (15).

The macroscopic equation associated with Eq. (13) is obtained by integrating it after multiplication by Z , using an expansion similar to Eq. (3) and retaining the lowest order term. The resulting macroscopic equation is identical to Eq. (4), which is the macroscopic equation associated with the master equation (1). The stationary macrostates of the system is defined by the roots of the r.h.s. of Eq. (4), viz. $A(\mathcal{Z}^s) = 0$. If the condition $A'(\mathcal{Z}^s) < 0$ is satisfied, the associated macrostate is stable. A detail discussion on stability, instability and bistability of stochastic processes can be found in Ref. [1].

In general, function $A(Z)$ is nonlinear. However, if $A(Z) = 0$ has only one stable root $Z = \mathcal{Z}^s$ (stable stationary macrostate), or there are more but at least one root is sufficiently away from the rest, then $A(Z)$ can be linearized about this macrostate. Consequently, a linear FPE, where drift is linear and diffusion coefficient is constant [1], can be derived. This derivation is achieved by expanding $A(Z)$ and $B(Z)$ about \mathcal{Z}^s , retaining the lowest nonzero term, and substituting them in Eq. (13):

$$\frac{\partial P(Z, t)}{\partial t} = -A'(\mathcal{Z}^s) \frac{\partial}{\partial Z} (Z - \mathcal{Z}^s) P(Z) + \frac{1}{2} B(\mathcal{Z}^s) \frac{\partial^2}{\partial Z^2} P(Z), \quad (16)$$

where, using Eq. (14),

$$A'(Z) = \frac{dA}{dZ} = - \sum_{n=1}^N n r'_n(Z) + \sum_{n=1}^M n g'_n(Z). \quad (17)$$

Equation (16) is a linear FPE, which is valid for fluctuations at the vicinity of \mathcal{Z}^s . This equation describes the Ornstein-Uhlenbeck process with a Gaussian solution at a stationary state with a mean and variance of

$$\langle Z \rangle^s = \mathcal{Z}^s, \quad (18)$$

$$\langle \langle Z \rangle \rangle^s = -\frac{1}{2} \frac{B(\mathcal{Z}^s)}{A'(\mathcal{Z}^s)}, \quad (19)$$

respectively, and a correlation of

$$\langle \langle Z(t)Z(t+u) \rangle \rangle^s = \langle \langle Z \rangle \rangle^s \exp\left(-\frac{u}{\tau_0}\right), \quad (20)$$

where $\tau_0 = -1/A'(\mathcal{Z}^s)$.

The procedure outlined in Appendix A can be also used to calculate MFPT in the linear FPE. Two specific MFPTs are the growth and dissipation times defined in Sec. I. The growth time is calculated by setting $L = \mathcal{Z}^s - Z$, $R = \mathcal{Z}^s + Z$, and $y = \mathcal{Z}^s$ in the integral solution in Eq. (A3), which is simplified for the linear FPE to

$$\frac{\tau_Z(\mathcal{Z}^s)}{\tau_0} = \frac{\Delta_Z^2}{2} {}_2F_2\left(1, 1; \frac{3}{2}, 2; \frac{\Delta_Z^2}{2}\right), \quad (21)$$

where $\Delta_Z = |Z - \mathcal{Z}^s|/\sqrt{\langle \langle Z \rangle \rangle^s}$ is the dimensionless deviation from the mean and ${}_2F_2$ is a generalized hypergeometric function [23]. On the other hand, the dissipation time is calculated

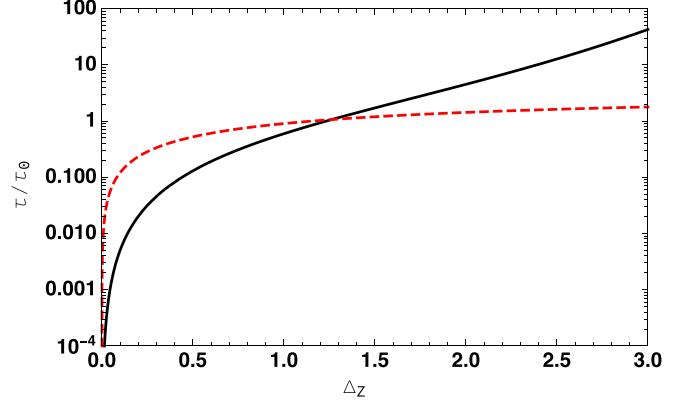


FIG. 1. Dimensionless growth (solid line) and dissipation (dashed line) times vs dimensionless deviation from the mean when the PDF is governed by a linear FPE.

by Eq. (A6)

$$\frac{\tau_s(Z)}{\tau_0} = \frac{1}{2} \pi \operatorname{erfi}\left(\frac{\Delta_Z}{\sqrt{2}}\right) - \frac{\tau_Z(\mathcal{Z}^s)}{\tau_0}. \quad (22)$$

Equations (21) and (22) are in a simplified form of the integral solutions previously provided [1,4] for a linear FPE. It is noted that, here, the process is not restricted to the one step assumption previously made [4].

Figure 1 displays the dimensionless growth time $\tau_Z(\mathcal{Z}^s)/\tau_0$ and the dimensionless dissipation time $\tau_s(Z)/\tau_0$ versus Δ_Z . Both times increase monotonically from zero. The dissipation time experiences a steep increase initially but its rate of increase rapidly drops. The growth time starts off with a slower rate but intersects with the dissipation time at $\Delta_Z = 1.26278$ and $\tau_Z(\mathcal{Z}^s)/\tau_0 = \tau_s(Z)/\tau_0 = 1.06319$. Then, the difference between the growth and dissipation times grows, becoming an order of magnitude larger at $\Delta_Z \sim 3$.

III. STOCHASTIC CHARGING OF A GRAIN IN A PLASMA

Consider a plasma with ion (electron) density of $n_{i(e)}$, temperature of $T_{i(e)}$, and mass of $m_{i(e)}$, and let $\lambda_D = \sqrt{\epsilon_0 k_B T_e / n_e e^2}$ and $\omega_{pe} = \sqrt{n_e e^2 / \epsilon_0 m_e}$ represent the Debye length and plasma frequency, respectively. Moreover, let $I_i(Z)$, $I_e(Z)$, and $I_s(Z)$ indicate the currents of ions, primary electrons, and secondary emitted electrons from the grain, respectively. Ions are assumed singly positively charged, however, the discussion here can be extended to include multiply charged ions [6]. Let $f_j(Z)$ represent the probability distribution of j electrons emitted from the grain in a single incident of primary electron attachment. This quantity is equivalent to the fraction of primary electrons that cause j secondary electrons to emit in a single primary electron attachment incident. If K represents the maximum number of secondary electrons that can be emitted in a single incident of the electron attachment, then $0 \leq j \leq K$ and $\sum_{j=0}^K f_j(Z) = 1$. It can be shown that $I_s(Z) = I_e(Z) \sum_{j=1}^K f_j(Z)$. If $N = 1$, $r_1(Z) = f_0(Z) I_e(Z)$, $M = K - 1$, and $g_n(Z) = f_{n+1}(Z) I_e(Z) + \delta_{1n} I_i(Z)$ in Eq. (1), where δ_{mn} is the Kronecker delta function, the master equation governing grain charging with ions, electrons and SEE in a plasma [10]. Using the rate equations above, the drift coefficient in Eq. (13)

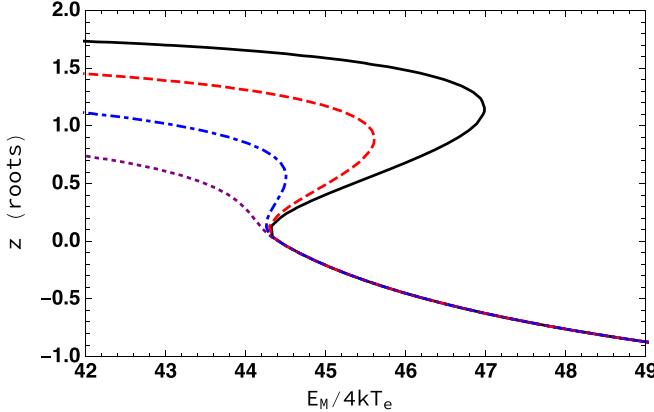


FIG. 2. Stationary macrostates (roots of the macroscopic equation at a stationary state) against $E_M/4kT_e$ near a triple-root situation for $E_M/4kT_s = 30$ (solid line), 32 (dashed line), 35 (dot-dashed line), and 40 (dotted line); $\delta_M = 15$.

is simplified to $A(Z) = -I_e(Z) + I_i(Z) + I_s(Z)$ and the r.h.s. of the macroscopic Eq. (4) is the net current to the grain.

The calculation of the currents of ions, primary electrons, and secondary electrons and the probability distribution of emission of secondary electrons is illustrated in Appendix B with the significant parameters noted below. A reference grain charge is defined by

$$\Omega = \frac{4\pi\epsilon_0 a k_B T_e}{e^2}, \quad (23)$$

where a represents the radius of the grain. It is noted that Ω defined by Eq. (23) was used as the system size [1] in the stochastic description of grain charging [5,6,10]. Also, a reference charging time scale is defined by

$$\tau_c = \frac{\Omega}{\Gamma} = \frac{\sqrt{2\pi}\lambda_D}{\omega_{pe}a}, \quad (24)$$

where

$$\Gamma = \pi a^2 n_e \sqrt{\frac{8k_B T_e}{\pi m_e}} = \frac{\Omega \omega_{pe} a}{\sqrt{2\pi}\lambda_D}, \quad (25)$$

which indicates the electron current to the uncharged grain. For SEE from the grain, T_s represents the temperature of the emitted secondary electrons, δ_M is the maximum yield which is around unity for metals and at the order 2 to 30 for insulators, and E_M is the peak primary electron energy, a model constant ranging from 300 to 2000 eV. The values of these two parameters for various dust materials can be found in Ref. [19].

The stationary grain charge macrostates, which correspond to the roots of Eq. (4) with the left-hand side (l.h.s.) set to zero, are plotted against $E_M/4kT_e$ in Fig. 2. Here, $z = Z/\Omega$ indicates the normalized charge. The four curves correspond to four different values of $E_M/4kT_s$. It could be seen in this figure that they collapse into a single curve for $z < 0$, which is attributed to the SEE current being independent from the SEE temperature as evident in Eq. (B3) for $z < 0$. A triple root situation is observed for $E_M/4kT_s = 30, 32$, and 35 while this situation does not encounter for $E_M/4kT_s = 40$. In the triple root situations, one of the roots is negative and stable (negative

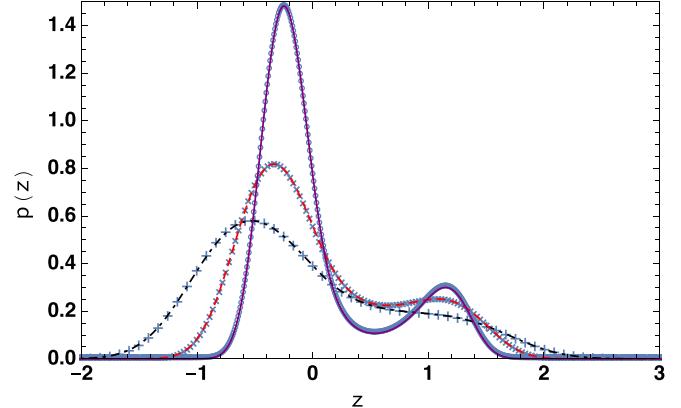


FIG. 3. Probability density function of the normalized grain charge ($z = Z/\Omega$) at a bistable state for grain radius of 100, 30, and 10 nm shown by solid, dashed, and dotted-dashed lines, respectively, through the Fokker-Planck equation, and shown by \circ , \times , and $+$, respectively, through the master equation; $\delta_M = 15$, $E_M/4kT_e = 45$, $E_M/4kT_s = 32$.

charge state) and the other two positive. The larger positive root is stable (positive charge state) and the smaller one is unstable. A single positive root situation is encountered on the left of the triple root region while a single negative root situation is on the right of this region.

IV. RESULTS AND DISCUSSION

Grains with a radius in the range of 10 to 100 nm suspended in a hydrogen plasma with $n_{i(e)} = 10^4 \text{ m}^{-3}$, $T_i = T_e = 2 \times 10^4 \text{ K}$ were considered. These values are relevant to interstellar dusty plasma condition [24].

Figure 3 shows the PDF of the normalized charge obtained by solving the master equation and separately by solving the Fokker-Planck equation, for a bistable state of grain charging (a triple root situation where there are two stable stationary macrostates) for three different grain sizes. The agreement between ME and FPE solutions is excellent. A bimodal distribution is distinguishable for a grain radius of 100 nm. The distribution of the grain charge exhibits bimodality however it is less obvious for a grain radius of 30 nm.

Figure 4 displays MFPT normalized by τ_c , versus grain radius. MFPT is calculated, using ME, and separately using the FPE. In the former approach, MFPT is obtained by integrating the PDF of FPT given in Eqs. (5) and (9). In the latter approach, it is obtained by Eqs. (A5) and (A6). Except for $R < 30 \text{ nm}$, excellent agreement is seen between two approaches in Fig 4. For $R < 30 \text{ nm}$, the difference between the approaches is much more pronounced for the dimensionless MFPT of a transition from the negative to positive macrostate, compared to the one from the positive to negative macrostate. The significant difference between ME and FPE results here could be attributed to the discreteness of charge, which is neglected in FPE but it is more critical for smaller grains. For the grain radius range considered here, the dimensionless MFPT of a transition from the stable positive charge macrostate to the negative charge macrostate experiences little change, exhibiting a constant value of around 2.5. On the other hand, the

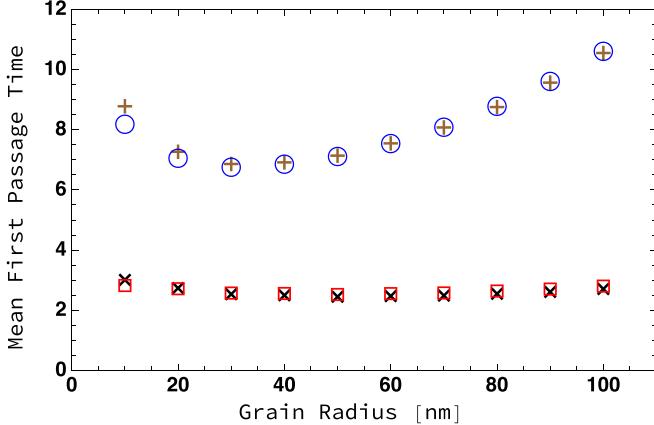


FIG. 4. MFPT normalized by τ_c , versus grain radius for a transition from the negative macrostate to the positive macrostate through master equation (+) and Fokker-Planck equation (○) and for a transition from the positive macrostate to the negative macrostate through master equation (\times) and Fokker-Planck equation (\square); see caption of Fig. 3 for parameter values.

one from the negative charge macrostate to the stable positive charge macrostate first descends, reaching a minimum value of around seven at a grain radius of around 30 nm, and then gradually rises with the increase of radius. The radius at which this minimum occurs seems to be correlated with how the shape of PDF of the grain charge changes with radius (Fig. 3). As seen in Fig. 3, there is a deep saddle point for the PDF for a radius of 100 nm whereas it does not exist for a radius of 10 nm. A saddle point is also seen for a radius of 30 nm; however, it is very shallow. It is found that the saddle point is deeper for a larger radius. At a given radius the MFPT from the negative macrostate to the positive macrostate is substantially larger than that from the positive macrostate to the negative macrostate, indicating that the system fluctuates longer at the negative charge state.

Figure 5 displays the PDF of the normalized FPT for three grain radii of 10, 30, and 100 nm, which are calculated, using Eqs. (5) and (9). The PDFs in the bottom panel, which is for the transition from the stable positive to negative macrostate, are wider than those in the top panel, which is for the reverse transition. In the top panel, the PDFs are similar for a dimensionless FPT larger than around 2. The grain charge is more populated around the negative charge macrostate for all three grain charge sizes, compared to the stable positive macrostate. That means a grain charge starting from the left macrostate will overall remain longer in this macrostate before transiting to the positive macrostate.

V. SUMMARY AND CONCLUSIONS

The absorbing boundary approach previously developed for calculation of FPT in the stochastic processes that are governed by one-step master equations [1], was extended to include multistep master equations. The restriction of jumps between adjacent sites in one step process is relaxed in multi-step processes. The outcome of this extension was formulas for calculation of MFPT and the PDF of FPT. The new approach was used to study FPT in the grain charging system

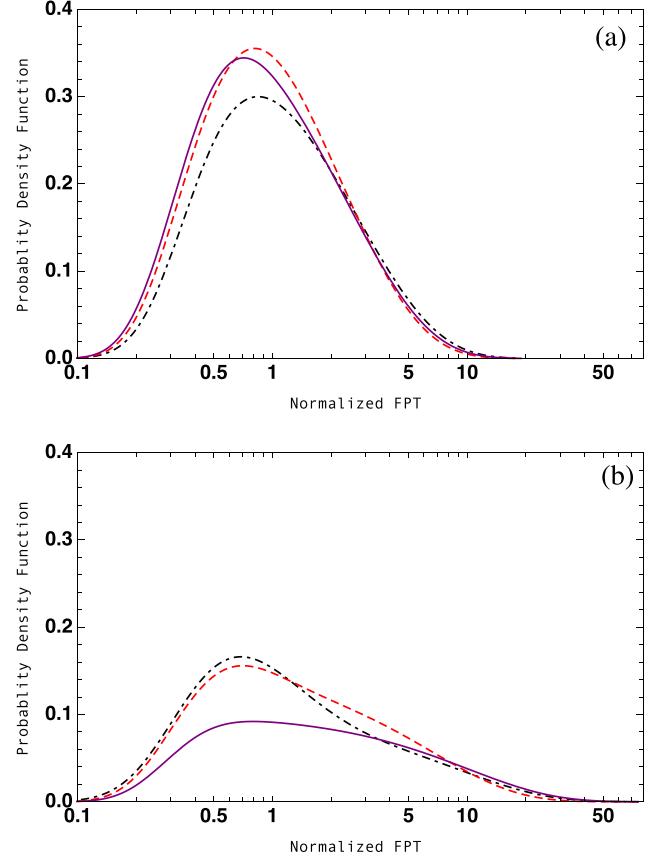


FIG. 5. Probability density function of FPT normalized by τ_c for grain radius of 100 (solid line), 30 (dashed line), and 10 nm (dotted-dashed line) for grain charge transitioning (a) from the positive macrostate to the negative macrostate; and (b) from the negative macrostate to the positive macrostate. See the caption of Fig. 3 for parameter values.

where a grain is charged by collecting ions and electrons from a plasma, and emitting secondary electrons as a result of the impact of the primary electrons. Depending on the plasma and grain parameters, such a grain charge system could have only one stationary stable macrostate or two stationary stable macrostates (bistable), one negative and the other positive that are separated by a third unstable positive macrostate. Furthermore, assuming continuity for the state variable, a Fokker-Planck equation was derived from the master equation of multistep processes. The extended absorbing boundary approach and a previous FPE based approach [22] were used to calculate the MFPT of the transitioning of charge between stable macrostates in bistable charging of grains for various grain radii. The MFPTs calculated by two approaches for a given grain radius were in excellent agreement except for very small grains. Very small grains possess small net elementary charges that the continuity assumption of charge, critical in the FPE description, may not be valid. For a given grain radius, the MFPT for a transition from the negative macrostate to the positive one was substantially larger than that for a transition in a reverse order. The dimensionless MFPT for a transition from the positive stable macrostate to the negative macrostate showed little sensitivity to the grain

radius. On the other hand, with the increase of the grain radius, it dropped first and then increased for the transition from the negative to the positive macrostate. The PDF of FPT, calculated by the extended absorbing boundary approach, was found substantially wider for a transition from the positive to negative macrostate, as compared to a transition from the negative to the positive macrostate. Also, the derived FPE was further simplified through a linearization approximation about a stationary macrostate to obtain a linear FPE [1]. Such an approximation is applicable about a macrostate if it is the only macrostate or if it is sufficiently distant from the rest of macrostates in a multiple macrostate situation. Using the linear FPE, two equations for calculation of dissipation and growth times were provided. When simplified to one-step processes, they were consistent with the dissipation and growth time equations previously provided [4] for grain charging through one-step processes.

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APPENDIX A: CALCULATION OF MFPT IN THE FOKKER-PLANCK EQUATION

Here, the methodology given by Gardiner [22] and Van Kampen [1] for the calculation of MFPT for a continuous stochastic process governed by a Fokker-Planck equation is presented. For a given process, this equation is available in two different forms, known as the forward equation and the backward equation. However, they are equivalent, as discussed by Gardiner [22]. The forward Fokker-Planck equation, which is commonly referred just as the Fokker-Planck equation, reads

$$\frac{\partial P(y, t)}{\partial t} = -\frac{\partial}{\partial y} A(y)P + \frac{1}{2} \frac{\partial^2}{\partial y^2} B(y)P. \quad (\text{A1})$$

The mean passage time $\tau(y)$ associated with this equation obeys

$$A(y) \frac{d\tau}{dy} + \frac{1}{2} B(y) \frac{d^2\tau}{dy^2} = -1, \quad (\text{A2})$$

which is derived by the use of a backward equation equivalent to Eq. (A1), as illustrated by Gardiner [22]. Equation (A2) can be solved by direct integration. Three solutions have been

previously developed for the range $L < y < R$, using three different sets of left and right boundary conditions at $y = L$ and $y = R$. Gardiner [22] provided the solution below when both boundary conditions are absorbing, i.e., $\tau(L) = \tau(R) = 0$, is

$$\begin{aligned} \tau(y) = 2 & \left[\int_L^y \frac{dy'}{\psi(y')} \int_y^R \frac{dy'}{\psi(y')} \int_L^{y'} \frac{dy'' \psi(y'')}{B(y')} \right. \\ & \left. - \int_y^R \frac{dy'}{\psi(y')} \int_L^y \frac{dy'}{\psi(y')} \int_L^{y'} \frac{dy'' \psi(y'')}{B(y')} \right] \Big/ \int_L^R \frac{dy'}{\psi(y')}, \end{aligned} \quad (\text{A3})$$

where

$$\psi(y) = \int_L^y \frac{2A(y')}{B(y')} dy'. \quad (\text{A4})$$

Gardiner [22] and Van Kampen [1] gave the following solution to Eq. (A2) when the right boundary condition (BC) is absorbing $\tau(R) = 0$ and the left BC is reflecting $d\tau/dy = 0$ at $y = L$:

$$\tau(y) = 2 \int_y^R \frac{dy'}{e^{\psi(y')}} \int_L^{y'} \frac{e^{\psi(y'')}}{B(y'')} dy''. \quad (\text{A5})$$

Similarly, when the left BC is absorbing, i.e., $\tau(L) = 0$ and the right BC is reflecting, i.e., $d\tau/dy = 0$ at $y = R$, the solution is [22]

$$\tau(y) = 2 \int_L^y \frac{dy'}{e^{\psi(y')}} \int_{y'}^R \frac{e^{\psi(y'')}}{B(y'')} dy''. \quad (\text{A6})$$

APPENDIX B: CALCULATION OF THE CURRENTS

The electron and ion currents to the the grain are calculated by the following equations in a Maxwellian plasma [6,10,24]:

$$I_e(Z) = \Gamma \times \begin{cases} 1 + \frac{Z}{\Omega} & Z \geq 0, \\ \exp\left(\frac{Z}{\Omega}\right) & Z < 0, \end{cases} \quad (\text{B1})$$

$$I_i(Z) = \Gamma \hat{n}_i \sqrt{\frac{\hat{T}_i}{\hat{m}_i}} \times \begin{cases} 1 - \frac{Z}{\hat{T}_i \Omega} & Z \leq 0, \\ \exp\left(-\frac{Z}{\hat{T}_i \Omega}\right) & Z > 0, \end{cases} \quad (\text{B2})$$

where $\hat{T}_i = T_i/T_e$, $\hat{m}_i = m_i/m_e$, and $\hat{n}_i = n_i/n_e$. The SEE current from the grain is calculated following Sternglass' theory [10,19,25]:

$$I_s(Z) = 3.7 \delta_M \Gamma \times \begin{cases} \left(1 + \frac{Z}{\Omega \hat{T}_s}\right) \exp\left(-\frac{Z}{\Omega \hat{T}_s} + \frac{Z}{\Omega}\right) F_{5,B}\left(\frac{E_M}{4k_B T_e}\right) & Z \geq 0, \\ \exp\left(\frac{Z}{\Omega}\right) F_5\left(\frac{E_M}{4k_B T_e}\right) & Z < 0, \end{cases} \quad (\text{B3})$$

where

$$F_5(x) = x^2 \int_0^\infty u^5 \exp(-xu^2 - u) du,$$

$$F_{5,B}(x) = x^2 \int_B^\infty u^5 \exp(-xu^2 - u) du,$$

where $B = \sqrt{4k_B T_e Z / \Omega E_M}$ and $\hat{T}_s = T_s/T_e$, where T_s is the temperature of the emitted secondary electrons. For the definition of remaining parameters in this equation, readers are referred to Sec. III.

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